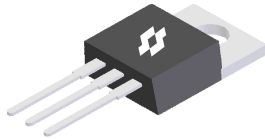


Product Summary

V_{DS}	$R_{DS(ON)_TYP}$	I_{D_MAX}
100 V	5.0 m Ω @ $V_{GS} = 10V$	171 A
	6.5 m Ω @ $V_{GS} = 4.5V$	
	5.2 m Ω @ $V_{GS} = 10V$	
	6.6 m Ω @ $V_{GS} = 4.5V$	

Features

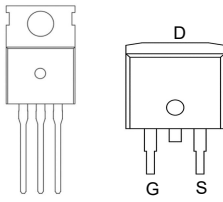
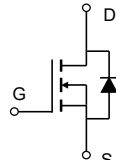
- Low On-Resistance
- Excellent FoM (figure of merit)
- 100% ΔV_{DS} & UIS & Rg Tested

TO220-3L


Top View

TO263-3L


Top View


 PIN Configuration
(Top View)


Schematic Diagram


Applications

- Motor controls
- DC/DC in Telecoms and Industrial
- High frequency switching, synchronous rectification

Mechanical Data

- Green Molding Compound
- Moisture Sensitivity: Level 1 per J-STD-020
- UL Flammability Classification Rating 94V-0

Ordering Information

Orderable Part Number	Package Type	Device Marking	Form	Quantity (pcs)
SMT10T06ALS	TO220-3L	10T06AL	Tube	50
SMT10T06ALT	TO263-3L	10T06AL	13" Tape&Reel	1,000

Maximum Ratings (@ $T_C = 25^\circ\text{C}$, unless otherwise specified.)

Parameter	Symbol	Value	Unit
Drain - Source Voltage	V_{DS}	100	V
Gate - Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ($V_{GS} = 10V$) ⁽¹⁾	I_D	128	A
		91	A
Pulsed Drain Current ⁽²⁾	I_{DM}	512	A
Single Pulse Avalanche Energy ⁽³⁾	E_{AS}	360	mJ
Single Pulse Avalanche Current ($L = 0.1\text{mH}$)	I_{AS}	42	A
Power Dissipation	P_D	205	W
		103	W
Junction & Storage Temperature Range	T_J, T_{STG}	-55 ~ +175	$^\circ\text{C}$

Thermal Characteristics

Parameter	Symbol	Typ.	Max.	Unit
Thermal Resistance, Junction-to-Ambient ⁽⁴⁾	$R_{\theta JA}$	36	45	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case ⁽⁵⁾	$R_{\theta JC}$	0.73	0.95	$^\circ\text{C/W}$

Electrical Characteristics (@ $T_J = 25^\circ\text{C}$, unless otherwise specified.)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit	
Off Characteristics ⁽⁶⁾							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	100	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 100V, V _{GS} = 0V	-	-	1.0	μA	
		T _J = 125°C	-	-	100	μA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V	-	-	±100	nA	
On Characteristics ⁽⁶⁾							
Gate Threshold Voltage	V _{GS(th)}	V _{GS} = V _{DS} , I _D = 250μA	1.2	1.7	2.5	V	
Static Drain-Source On-Resistance	R _{DS(on)}	V _{GS} = 10V, I _D = 20A	TO263-3L	-	5.0	6.0	mΩ
			TO220-3L	-	5.2	6.2	mΩ
		V _{GS} = 4.5V, I _D = 15A	TO263-3L	-	6.5	7.7	mΩ
			TO220-3L	-	6.6	7.9	mΩ
Forward Transconductance	g _{fs}	V _{DS} = 5.0V, I _D = 20A	-	51	-	S	
Diodes Forward Voltage	V _{SD}	I _S = 2.0A, V _{GS} = 0V	-	0.7	1.2	V	
Dynamic Characteristics ⁽⁷⁾							
Input Capacitance	C _{iss}	V _{DS} = 50V, V _{GS} = 0V, f = 1MHz	-	2022	-	pF	
Output Capacitance	C _{oss}		-	972	-	pF	
Reverse Transfer Capacitance	C _{rss}		-	23	-	pF	
Gate Resistance	R _g	V _{GS} = 0V, V _{DS} = 0V, f = 1MHz	-	1.0	-	Ω	
Switching Characteristics ⁽⁷⁾							
Turn-On DelayTime	t _{d(on)}	V _{GS} = 10V, V _{DS} = 50V I _D = 20A, R _{GEN} = 3.0Ω	-	4.3	-	ns	
Rise Time	t _r		-	7.6	-	ns	
Turn-Off DelayTime	t _{d(off)}		-	30	-	ns	
Fall Time	t _f		-	19	-	ns	
Gate Charge Characteristics ⁽⁷⁾							
Total Gate Charge (V _{GS} = 10V)	Q _g	V _{DS} = 50V, I _D = 20A V _{GS} = 10V	-	38	-	nC	
Total Gate Charge (V _{GS} = 4.5V)	Q _g		-	19	-	nC	
Gate-Source Charge	Q _{gs}		-	5.2	-	nC	
Gate-Drain Charge	Q _{gd}		-	8.1	-	nC	
Gate Plateau Voltage	V _{plateau}		-	2.7	-	V	
Drain-Source Diode Characteristics ⁽⁷⁾							
Body Diode Reverse Recovery Time	t _{rr}	I _F = 20A, dI/dt = 100A/μs,	-	55	-	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	T _J = 25°C	-	102	-	nC	
Diode Forward Current	I _S	T _C = 25°C	-	-	171	A	

Notes:

1. This current is chip limited, which is calculated based on R_{thjc} .
2. This current is calculated on single pulse with 10us Single Pulse.
3. Defined by design, not subject to production test, E_{AS} condition: $T_J = 25^\circ\text{C}, V_{DD} = 50V, V_{GS} = 10V, L = 1.0\text{mH}$.
4. Device mounted on FR-4 substrate PC board with 2oz copper in 1inch square cooling area.
5. Thermal resistance from junction to the exposed pad.
6. Short duration pulse test used to minimize self-heating effect.
7. Defined by design, not subject to production.

Typical Electrical and Thermal Characteristics

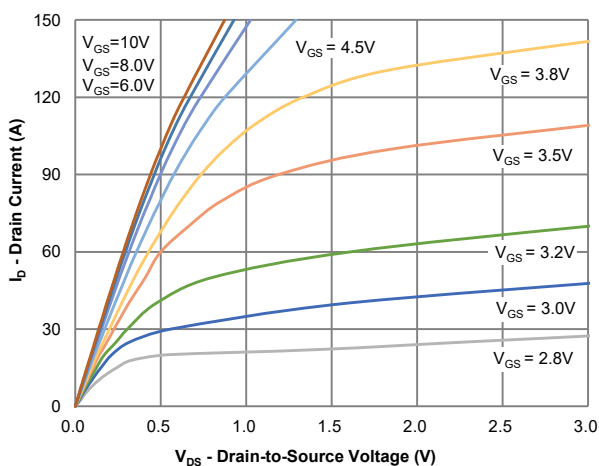


Figure 1: Output Characteristics

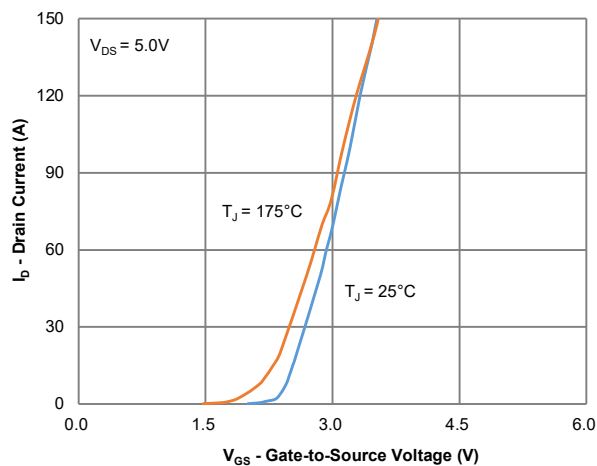


Figure 2: Transfer Characteristics

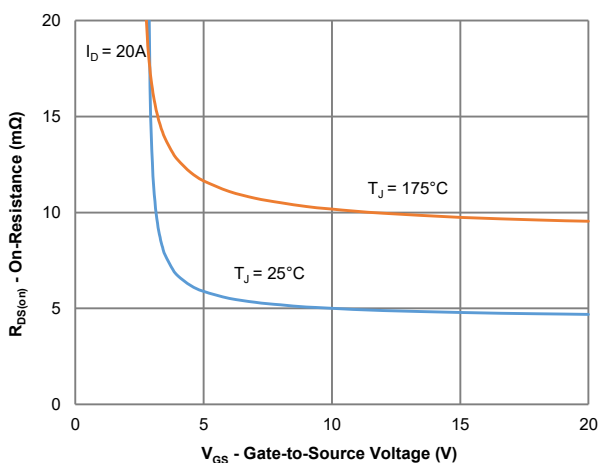


Figure 3: On-Resistance vs. Gate-Source Voltage

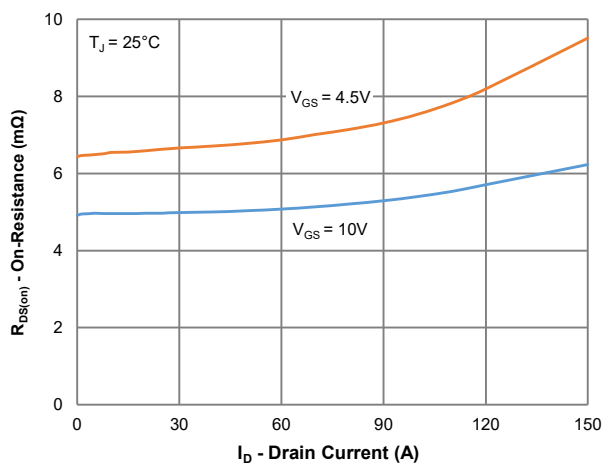


Figure 4: On-Resistance vs. Drain Current and Gate Voltage

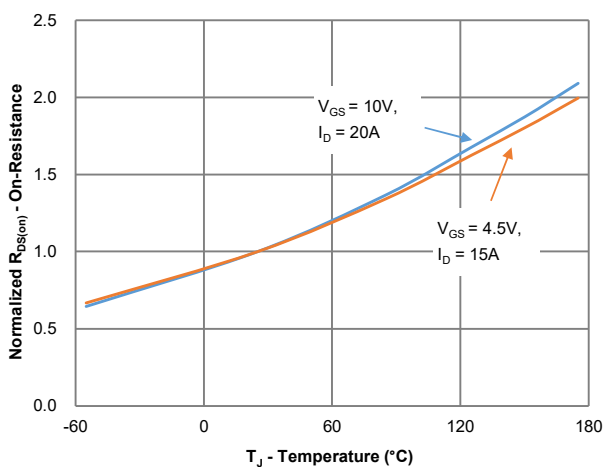


Figure 5: On-Resistance vs. Junction Temperature

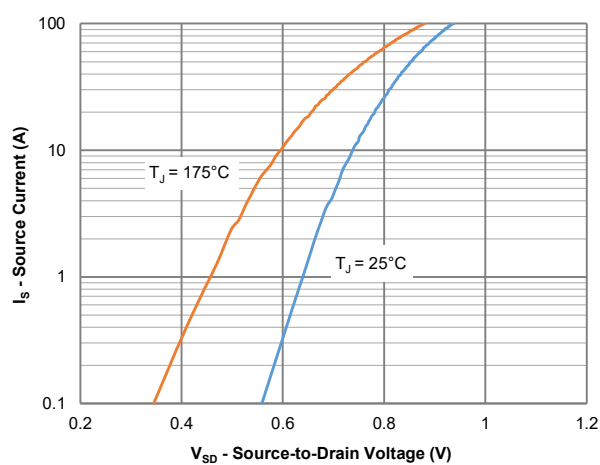


Figure 6: Source-Drain Diode Forward Voltage

Typical Electrical and Thermal Characteristics

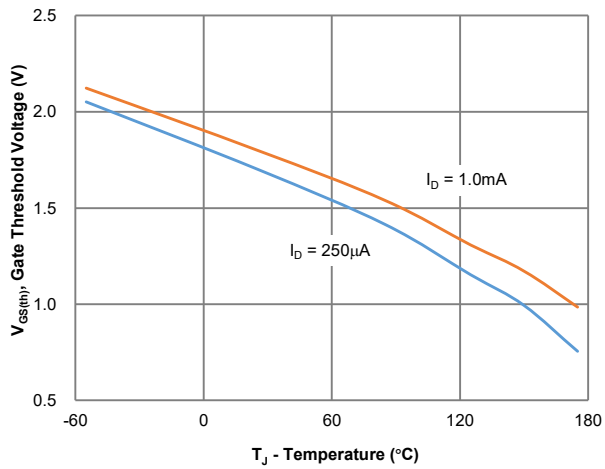


Figure 7: Gate Threshold Variation vs. Junction Temperature

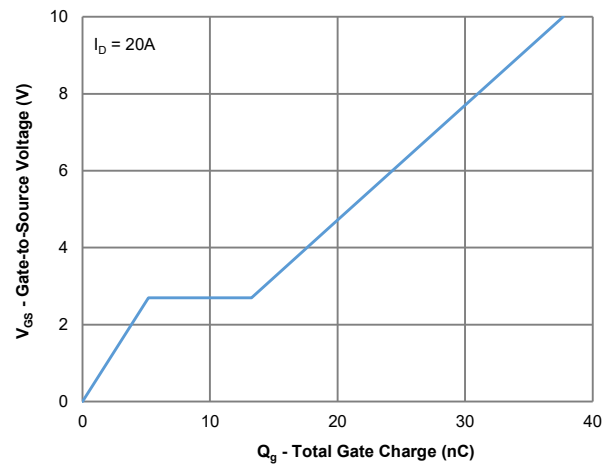


Figure 8: Gate Charge Characteristics

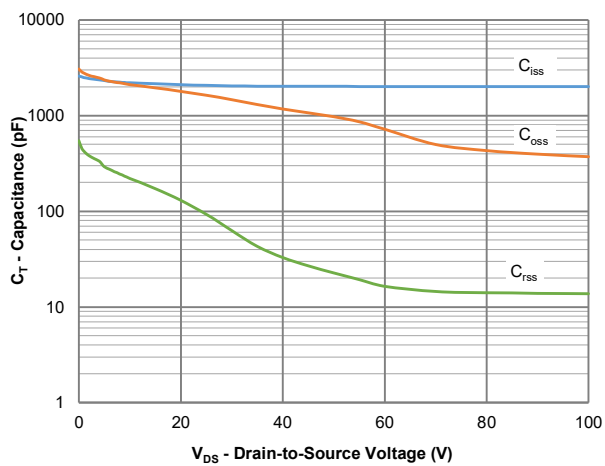


Figure 9: Capacitance Characteristics

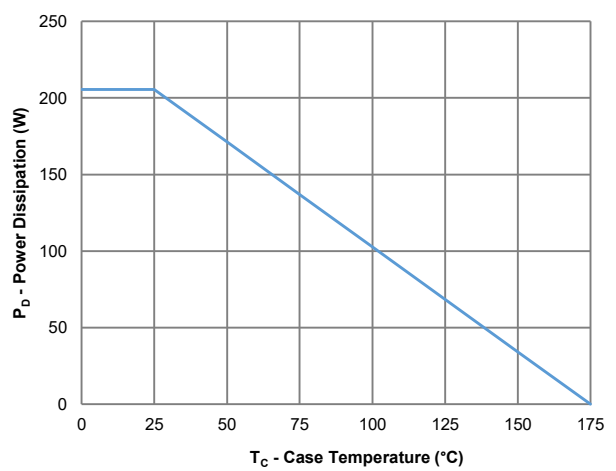


Figure 10: Power Derating

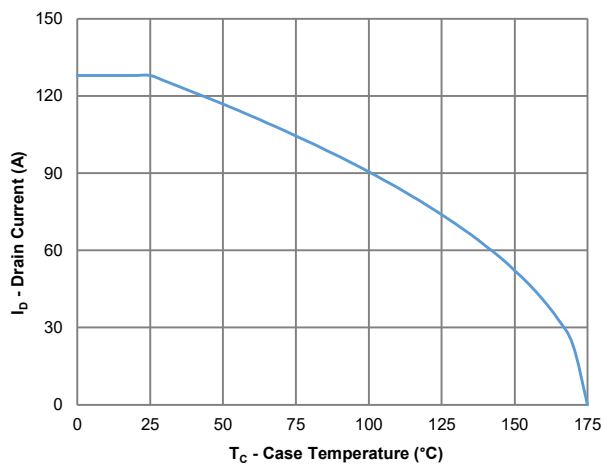


Figure 11: Current Derating

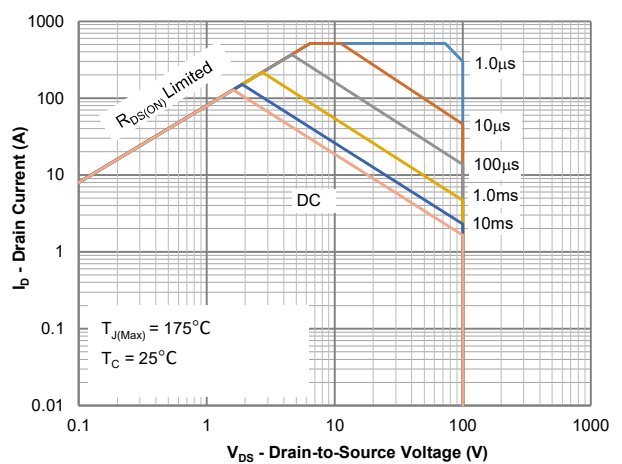
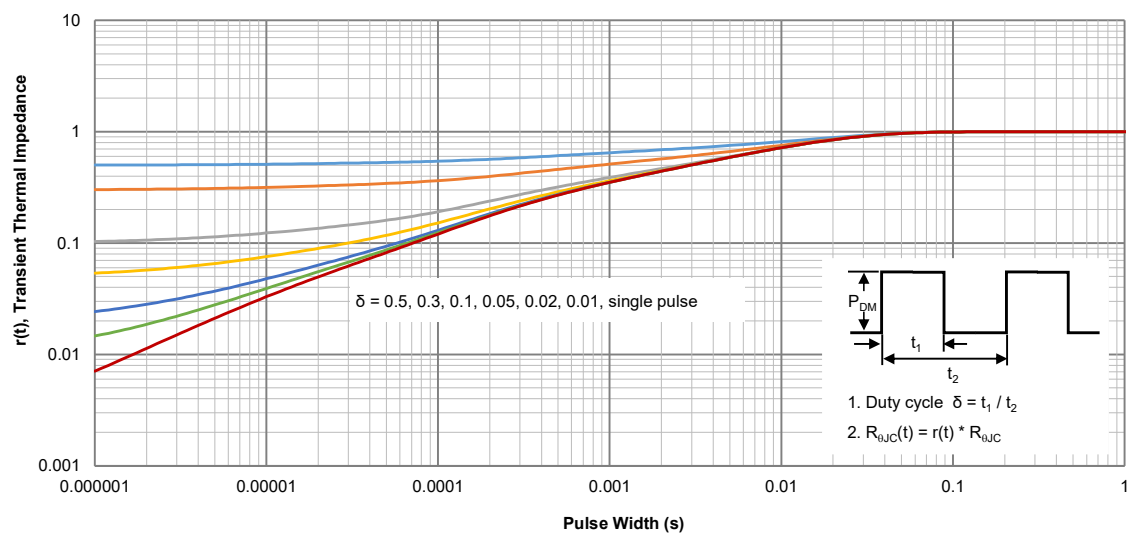
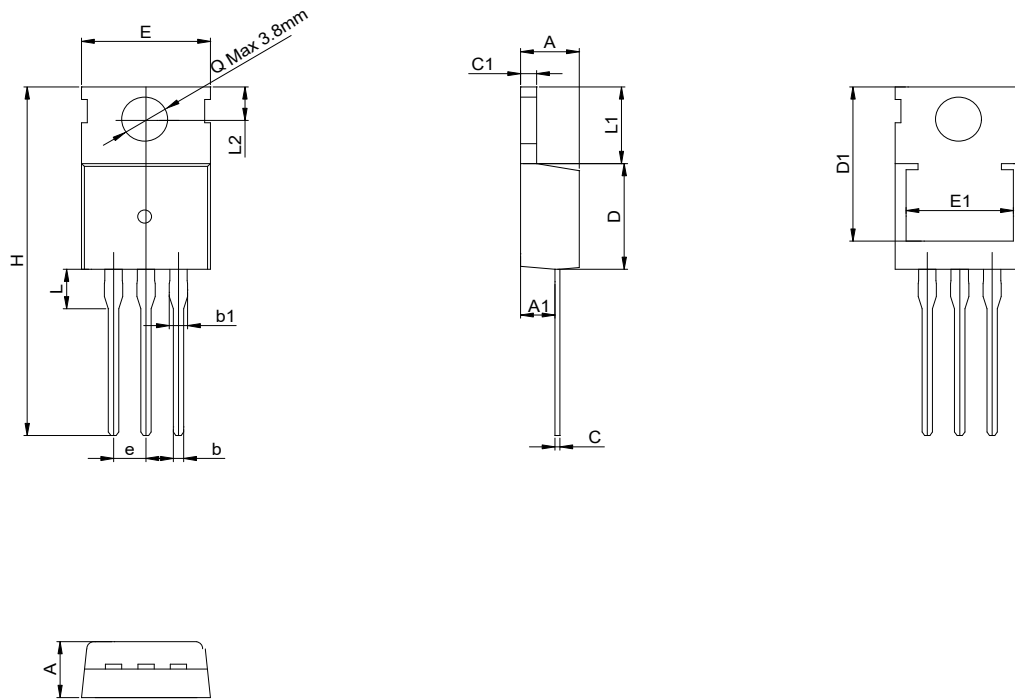


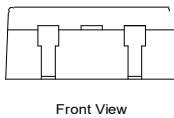
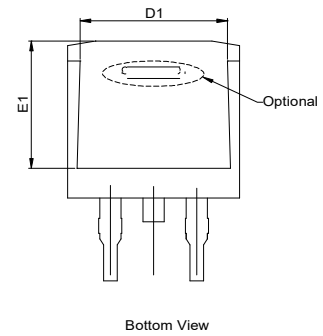
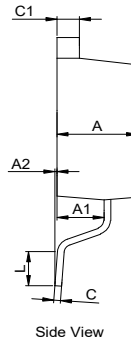
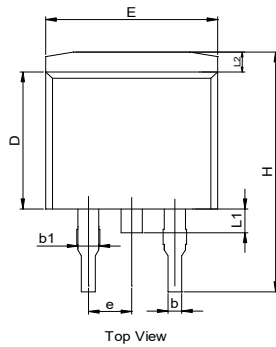
Figure 12: Safe Operating Area

Typical Electrical and Thermal Characteristics

Figure 13: Normalized Maximum Transient Thermal Impedance

TO220-3L Package Outline
Package Outline

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
2. ALL DIMENSIONS IN MILLIMETER (ANGLE IN DEGREE).
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH.

DIM.	MILLIMETER		
	MIN.	NOM.	MAX.
A	4.35	4.50	4.70
A1	2.20	2.30	3.00
b	0.70	0.80	0.95
b1	1.10	1.30	1.50
C	0.45	0.50	0.60
C1	1.23	1.30	1.40
H	28.00	28.80	29.80
D	8.80	9.21	9.90
D1	12.80	13.20	13.60
E	9.70	10.00	10.50
E1	7.40	8.00	8.60
L	--	--	3.80
L1	6.25	6.50	6.90
L2	2.40	2.90	3.05
e	2.54 BSC		

TO263-3L Package Outline
Package Outline


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
 2. ALL DIMENSIONS IN MILLIMETER (ANGLE IN DEGREE).
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH.

DIM.	MILLIMETER		
	MIN.	NOM.	MAX.
A	4.20	4.50	4.70
A1	2.30	--	2.85
A2	0.00	0.10	0.25
b	0.70	0.80	0.95
b1	1.15	1.30	1.70
C	0.30	0.50	0.60
C1	1.15	1.30	1.42
H	14.00	15.20	15.88
D	8.50	9.20	9.60
D1	6.80	7.75	8.00
E	9.78	10.00	10.36
E1	6.80	7.95	8.10
L	1.50	--	2.80
L1	--	--	1.75
L2	1.35 REF		
e	--	2.54	--

Recommended Soldering Footprint :
